L Number	Hits	Search Text	DB	Time stamp
1	3083	(polysilicon and capacitor).clm.	USPAT; US-PGPUB	2003/05/13 19:08
2	46	(polysilicon and capacitor and method).ti.	USPAT; US-PGPUB	2003/05/13 19:08
3	34	(bubbles and capacitor).clm.	USPAT; US-PGPUB	2003/05/13 19:08
4	213	(rough$4 and capacitor).ab.	USPAT; US-PGPUB	2003/05/13 19:09
5	37	(rough$4 and bubbles).ab.	USPAT; US-PGPUB	2003/05/13 19:09
6	13	(rough$4 and capacitor and etch).ab.	USPAT; US-PGPUB	2003/05/13 19:09
8	41	(rough$4 and capacitor and etch$3).ab.	USPAT; US-PGPUB	2003/05/13 19:10
9	437	rough$4 same capacitor same etch$3	USPAT; US-PGPUB	2003/05/13 19:11
10	3	(rough$4 same capacitor same etch$3) and bubbles	USPAT; US-PGPUB	2003/05/13 19:12
11	539	(rough$4 adj surface) same capacitor	USPAT; US-PGPUB	2003/05/13 19:13
-	3079	(polysilicon and capacitor).clm.	USPAT; US-PGPUB	2003/05/13 19:07
-	273	(polysilicon and capacitor and solution).clm.	USPAT; US-PGPUB	2003/05/13 19:08